

### Advertisement for the post of Research Associate

Applications are invited from Indian citizens in the given format for an interview for one post of Research Associate in the **Department of Electronics and Communication Engineering**, NIT Silchar, under **CSIR-EMR II sponsored project**, Govt. of India. The details are mentioned below:

#### Project Details:

<b>Title of the project</b>	Hetero-Junction Tunnel FETs: Characterization, modelling and simulation of Electrical Parameters
<b>Project Duration</b>	02 years
<b>Sponsoring Agency</b>	CSIR, EMR-II, Human Resource Development Group , CSIR Complex, Library Avenue, Pussa, New Delhi-110012
<b>Name of the Post</b>	Research Associate
<b>No. of post</b>	01
<b>Name and Address of Principal Investigator</b>	<b>Prof. S Baishya,</b> Professor, ECE Dept., NIT Silchar
<b>Name and Address of Co-Investigator</b>	<b>Dr. Brinda Bhowmick</b> Asst. Professor, ECE Dept., NIT Silchar

#### Other Details:

<b>Essential qualifications:</b>	The minimum qualifications: Ph.D. awarded or Thesis submitted in the area of semiconductor devices <b>OR</b> ME/M.Tech. in relevant area with 3 years of research, teaching and design, and development experience.
<b>Age limit</b>	Not more than 35 Years.
<b>Salary</b>	Rs. 36,000/ per month
<b>Relaxation on Age</b>	The upper age limit is relaxable upto 5 years in the case of candidates belonging to SC/ST/OBC/women physically handicapped candidates.
<b>Last date of submission of application through e-mail</b>	23 <sup>th</sup> Feb, 2018 brindabhowmick@gmail.com
Tentative date of interview:	Candidates should send their applications form (format attached) and self-attested necessary documents (scan copy) to the Co-Investigator only through e-mail to <a href="mailto:brindabhowmick@gmail.com">brindabhowmick@gmail.com</a> . Tentative date of interview: 28.02.2018
Other conditions	<ul style="list-style-type: none"><li>No TA/DA will be paid to appear in the interview and/or joining.</li></ul>

	<ul style="list-style-type: none"> <li>All the terms &amp; conditions for this recruitment will be as per the guidelines of the sponsoring agency and NIT Silchar.</li> </ul>
Call for interview	Only shortlisted candidates will be intimated through e-mail to appear for the interview. Candidates are advised to check their emails regularly.
No objection certificate	Employed candidate is to submit No Objection Certificate (NOC) from his/her employer at the time of interview.
Institute right	The Institute reserves the right to cancel the recruitment without assigning any reason thereof.
Signing of Agreement	Selected candidates shall have to sign an agreement at the time of joining.

National Institute of Technology Silchar

APPLICATION

PASTE PASSPORT  
SIZE PHOTO

for the post of .....

1. Project Title.....  
.....  
.....
2. Department:
3. Name of the applicant (in block letters):
4. Father's/Husband's Name:
5. Date of Birth (DD/MM/YYYY):
6. Age as on 31<sup>st</sup> Jan, 2018:
7. Postal Address:

E-mail:

Phone no.:

8. Permanent Address:

9. Nationality:

10. Marital Status:

11. Whether belongs to SC/ST/PH/OBC: (If yes, attach certificate):

12. Educational Qualification: (Starting from Class X)

Exam Passed	Board/ University	Year of passing	Division/ Class	% of marks/CPI	Subjects

13. NET/GATE Examinations Passed:

I. NET

II. GATE

Subject	Qualifying date	Valid upto		Subject	Score	

14. Details of employments, if any:

Sl. No.	Name of the Organization	Name of the post	Period	Scale of pay and present pay	Nature of duty

15. Any other relevant information that you may like to furnish:

### Declaration

I declare that the above information are true and correct to the best of my knowledge and belief.

Date:

Place:

Signature of the applicant